

Low-Voltage SPDT Analog Switch UM3156 SC70-6/SC88/SOT363

General Description

The UM3156 is an advanced CMOS analog switch fabricated with silicon gate CMOS technology. It achieves very low propagation delay and $R_{\rm DS(ON)}$ resistances while maintaining CMOS low power dissipation. These make it ideal for portable and battery power applications.

The switch conducts signals within power rails equally well in both directions when on, and blocks up to the power supply level when off. Break-before-make is guaranteed.

The select pin has over-voltage protection that allows voltages above V_{CC} , up to 6.5V to be present on the pin without damage or disruption of operation of the part, regardless of the operating voltage.

The UM3156 can maintain low power consumption for rail-to-rail signaling as long as the control signal input is held at a level that is greater than V_{IH} minimum and less than V_{IL} maximum by improving the control circuitry input buffer. So the part can be used in mixed voltage rail environments, especially services the mobile handset applications very well allowing for the direct interface with baseband processor general purpose I/Os, and it is no longer necessary to have the control input equal to V_{CC} to maintain low power consumption

Applications

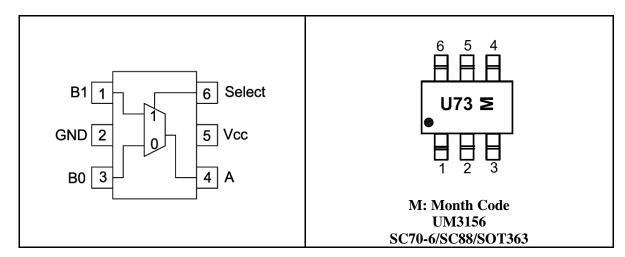
- Sample-and-Hold Circuits
- Battery-Powered Equipment
- Audio and Video Signal Routing
- Communication Circuits

Features

- Control Inputs are 5V Tolerant
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 1.65V to 5.5V Single-Supply Operation
- ESD Performance: Human Body Model>2kV Machine Model>200V
- SC70-6/SC88/SOT363 Package
- Pb-Free Package

Pin Configurations

Top View





Ordering Information

Part Number	art Number Packaging Type		Shipping Qty	
UM3156	SC70-6/SC88/SOT363	U73	3000pcs/7 Inch Tape & Reel	

Function Table

Select Input	Function			
L	B0 Connected to A			
Н	B1 Connected to A			

Absolute Maximum Ratings

Symbol	Parameter	Limit	Unit	
V_{CC}	Supply Voltage	-0.5 to +6.5		
V_{S}	DC Switch Voltage (Note 1)	-0.5 to $(V_{CC}+0.5)$	V	
$V_{\rm IN}$	DC IN Voltage (Note 1)	-0.5 to +6.5		
I_{IK}	DC Input Diode Current @ V _{IN} <0V	-50		
I_{OUT}	DC Output Current	128	mA	
$I_{\text{CC}}/I_{\text{GND}}$	DC V _{CC} or Ground Current	+100		
T_{J}	Junction Temperature Under Bias	+150		
T_{STG}	Storage Temperature	-65 to +150	${\mathcal C}$	
$T_{ m L}$	Junction Lead Temperature (Soldering, 10 Seconds)	260		
$\theta_{ m JA}$	Thermal Resistance	350	°C/W	
P_{D}	Power Dissipation @ +85 °C	180	mW	

Note 1: The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Ratings (Note 2)

Symbol	Parameter	Limit	Unit
V_{CC}	Supply Voltage Operating	1.65 to 5.5	
$V_{\rm IN}$	Switch Input Voltage	0 to V _{CC}	V
$V_{\rm IN}$	Select Input Voltage	0 to V _{CC}	V
V _{OUT}	Output Voltage	0 to V _{CC}	
T_{A}	Operating Temperature	-55 to +125	${\mathbb C}$
t_r, t_f	Input Rise and Fall Time Control Input V _{CC} =2.3V to 3.6V	0 to 10	ns/V
	Control Input V _{CC} =4.5V to 5.5V	0 to 5.0	

Note 2: Select input must be held HIGH or LOW, it must not float.



Electrical Characteristics

a	Parameter	Test Conditions	Vcc (V)	Temp	Limits	Limits (-40 ℃ to 85 ℃)		
Symbol					Min	Тур	Max	Unit
DC Electrical Characteristics								
	Analog Signal Range		Vcc	Full	0		Vcc	V
$I_{\rm IN}$	Input Leakage Current	0≤V _{IN} ≤5.5V	0 to 5.5	Room Full		±0.05	±0.1 ±1	μΑ
Ioff	OFF State Leakage Current	0≤A, B≤Vcc	1.65 to 5.5	Room Full		±0.05	±0.1 ±1	μΑ
			1.65 to 2.3		1.1			
			2.3 to 2.7		1.4			
V_{IH}	Input High Voltage		2.7 to 3.6	Full	1.8			V
			3.6 to 4.3		2.1			
			4.3 to 5.5		2.6			
			1.65 to 2.3				0.4	
			2.3 to 2.7				0.7	V
$V_{IL} \\$	Input Low Voltage		2.7 to 3.6	Full			1.0	
			3.6 to 4.3				1.3	
			4.3 to 5.5				1.5	
Icc	Quiescent Supply Current	V _{IN} =V _{CC} or GND I _O =0	5.5	Room Full			1.0 10	μΑ
		V _{IN} =0V, I _O =30mA V _{IN} =2.4V, I _O =-30mA V _{IN} =4.5V, I _O =-30mA	4.5	Full		3.0 4.0 4.5	7.0 12 15	
Ron	On-Resistance (Note 3)	V _{IN} =0V, I _O =24mA V _{IN} =3V, I _O =-24mA	3.0	Full		4.0 6.0	9.0 20	Ω
		V _{IN} =0V, I _O =8mA V _{IN} =2.3V, I _O =-8mA	2.3	Full		5.0 8.0	12 30	
		V _{IN} =0V, I _O =4mA V _{IN} =1.65V, I _O =-4mA	1.65	Full		6.5 15	20 50	
	On Resistance Over Signal Range	$I_{A}=-30mA$ $0\leq V_{Bn}\leq V_{CC}$	4.5	Full			25	Ω
RRANGE		$I_{A}=-24mA$ $0\leq V_{Bn}\leq V_{CC}$	3.0	Full			50	
	(Note 3, 7)	$I_A=-8mA$, $0 \le V_{Bn} \le V_{CC}$	2.3	Full			100	
		$I_A=-4mA$, $0\leq V_{Bn}\leq V_{CC}$	1.65	Full			300	
$\Delta R_{ m ON}$	On Resistance	I _A =-30mA, V _{Bn} =3.15V	4.5	Room		0.15		Ω
	Match Between Channels	I _A =-24mA, V _{Bn} =2.1V	3.0	Room		0.2		
	(Note 3, 4, 5)	$I_A=-8mA$, $V_{Bn}=1.6V$	2.3	Room		0.5		
		$I_A = -4mA, V_{Bn} = 1.15V$	1.65	Room		0.5		
	On Resistance Flatness	I _A =-30mA, 0≤V _{Bn} ≤V _{CC}	5.0	Room		6.0		
R _{FLAT}		I _A =-24mA, 0≤V _{Bn} ≤V _{CC}	3.3	Room		12		Ω
	(Note 3, 4, 6)	$I_A=-8mA$, $0 \le V_{Bn} \le V_{CC}$	2.5	Room		28		
		$I_A=-4mA$, $0\leq V_{Bn}\leq V_{CC}$	1.8	Room		125		



Electrical Characteristics (Continued)

Symbol	Parameter	Test Conditions	V _{CC} (V)	Temp	Limits (-40 ℃ to 85 ℃)			Unit
Symbol	Tarameter rest Conditions vec (v) remp		remp	Min	Тур	Max	UIII	
AC Elect	AC Electrical Characteristics							
t _{PHL} t _{PLH}	Propagation Delay Bus to Bus (Note 9)	V _I =OPEN	1.65 to1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Full			1.5 1.0 0.8	ns
t _{PZL} t _{PZH}	Output Enable Time Turn On Time (A to Bn)	V _I =2×V _{CC} for t _{PZL} V _I =0V for t _{PZH}	1.65 to1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Full	7.0 3.5 2.5 1.5		26 15 8.6 6.2	ns
tplz tphz	Output Disable Time Turn Off Time (A Port to B Port)	V _I =2×V _{CC} for t _{PLZ} V _I =0V for t _{PHZ}	1.65 to 1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Full	3.0 2.0 1.7 0.8		13 7.5 5.3 3.8	ns
$t_{ m D}$	Break Before Make Time (Note 8)		1.65 to 1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Full	0.5 0.5 0.5 0.5			ns
Qinj	Charge Injection (Note 8)	C_L =0.1nF, V_{GEN} =0V, R_{GEN} =0 Ω	5.0 3.3	Room		9.0 4.0		pC
O _{IRR}	Off Isolation (Note 10)	R_L =50 Ω , f=10MHz	1.65 to 5.5	Room		-60		dB
Xtalk	Crosstalk	R_L =50 Ω , f=10MHz	1.65 to 5.5	Room		-54		dB
BW	-3 dB Bandwidth	$R_L=50\Omega$	1.65 to 5.5	Room		230		MHz
THD	Total Harmonic Distortion (Note 8)	$\begin{array}{c} R_L \!\!=\!\! 600\Omega \\ 0.5 V_{P\text{-}P} \\ f \!\!=\!\! 600 Hz \text{ to } 20 kHz \end{array}$	5.0	Room		0.011		%
Capacita	nce							
Cin	IN Pin Input Capacitance (Note 11)	V _{CC} =0V				2.5		pF
Сю-в	B Port Off Capacitance (Note 11)	V _{cc} =5.0V				7.5		pF
C _{IOA-ON}	A Port Capacitance when Switch is Enabled (Note 11)	$V_{\rm CC}$ =5.0 V				20.1		pF

- Note 3: Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B Ports).
- Note 4: Parameter is characterized but not tested in production.
- Note 5: $\Delta R_{ON} = |R_{ON(B0)} R_{ON(B1)}|$ measured at identical V_{CC} , temperature and voltage levels.
- Note 6: Flatness is defined as the difference between the maximum and minimum value of On Resistance over the specified range of conditions.
- Note 7: Guaranteed by design.
- Note 8: Guaranteed by design.
- Note 9: This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On Resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).
- Note 10: Off Isolation=20log10 [V_A/V_{Bn}].
- Note 11: T_A=+25 ℃, f=1MHz. Capacitance is characterized but not tested in production.



Test Circuits/Timing Diagrams

NOTE: Input driven by 50 Ω source terminated in 50 Ω NOTE: C_L includes load and stray capacitance NOTE: Input PRR = 1.0 MHz; t_W = 500 ns

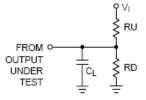
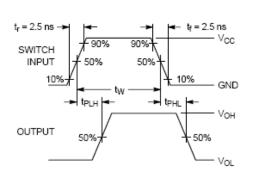


Figure 1. AC Test Circuit



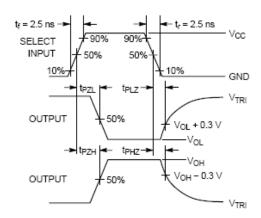
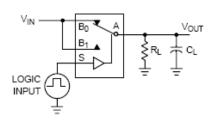


Figure 2. AC Waveforms



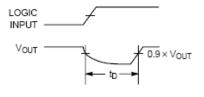
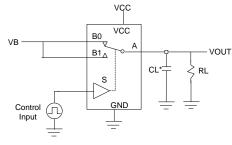
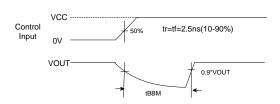


Figure 3. Break Before Make Interval Timing





CL* includes fixture and stray capacitance

Figure 4. Break-Before-Make Timing



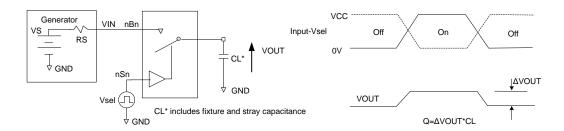


Figure 5. Charge Injection Test

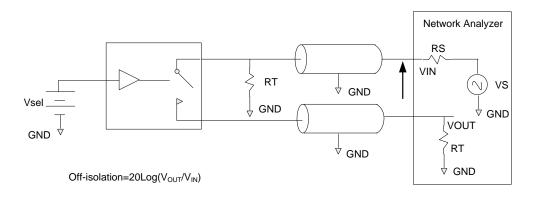
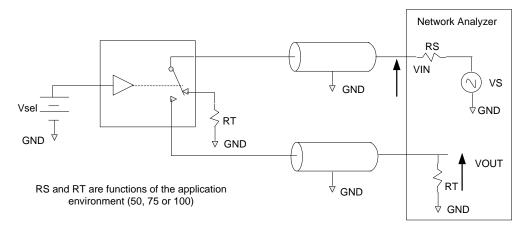


Figure 6. Off-Isolation



Crosstalk=20Log(V_{OUT}/V_{IN})

Figure 7. Non-Adjacent Channel-to-Channel Crosstalk

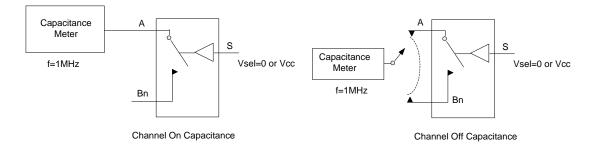


Figure 8. On/Off Capacitance Measurement Setup



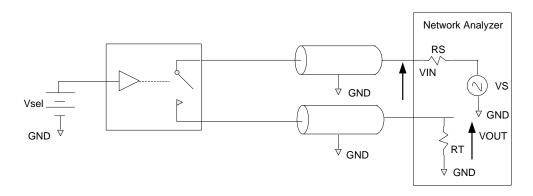


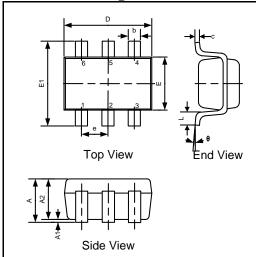
Figure 9. Bandwidth



Package Information

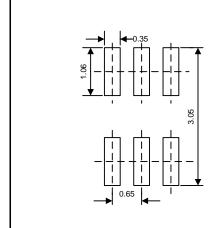
UM3156 SC70-6/SC88/SOT363

Outline Drawing



DIMENSIONS							
C11	MILLIMETERS			INCHES			
Symbol	Min	Тур	Max	Min	Тур	Max	
A	0.90	-	1.10	0.035	-	0.043	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A2	0.90	ı	1.00	0.035	-	0.039	
b	0.10	0.25	0.35	0.004	0.010	0.014	
c	0.08	0.11	0.22	0.003	0.004	0.009	
D	1.80	2.15	2.20	0.071	0.085	0.087	
Е	1.15	1.30	1.35	0.045	0.051	0.053	
E1	2.00	-	2.45	0.079	-	0.096	
e	0.65BSC			C	0.026BS	C	
L	0.25	-	0.46	0.010	-	0.018	
θ	0 °	-	8°	0 °	-	8°	

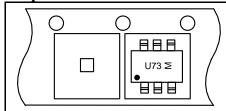
Land Pattern



NOTES:

- 1. Compound dimension: 2.15×1.30;
- 2. Unit: mm;
- 3. General tolerance ± 0.05 mm unless otherwise specified;
- 4. The layout is just for reference.

Tape and Reel Orientation





GREEN COMPLIANCE

Union Semiconductor is committed to environmental excellence in all aspects of its operations including meeting or exceeding regulatory requirements with respect to the use of hazardous substances. Numerous successful programs have been implemented to reduce the use of hazardous substances and/or emissions.

All Union components are compliant with the RoHS directive, which helps to support customers in their compliance with environmental directives. For more green compliance information, please visit:

http://www.union-ic.com/index.aspx?cat_code=RoHSDeclaration

IMPORTANT NOTICE

The information in this document has been carefully reviewed and is believed to be accurate. Nonetheless, this document is subject to change without notice. Union assumes no responsibility for any inaccuracies that may be contained in this document, and makes no commitment to update or to keep current the contained information, or to notify a person or organization of any update. Union reserves the right to make changes, at any time, in order to improve reliability, function or design and to attempt to supply the best product possible.